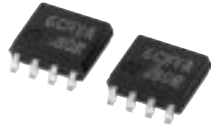


FY6ACH-02A

HIGH-SPEED SWITCHING USE

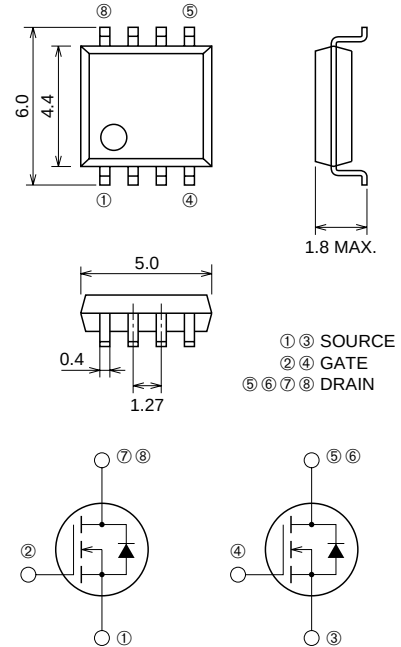
FY6ACH-02A



- 2.5V DRIVE
- V_{DS} 20V
- $r_{DS(ON)}$ (MAX) $30m\Omega$
- I_D 6A

OUTLINE DRAWING

Dimensions in mm



SOP-8

APPLICATION

Motor control, Lamp control, Solenoid control
DC-DC converter, etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	20	V
V_{GS}	Gate-source voltage	$V_{DS} = 0V$	± 10	V
I_D	Drain current		6	A
I_{DM}	Drain current (Pulsed)		42	A
I_{DA}	Avalanche drain current (Pulsed)	$L = 10\mu H$	6	A
I_S	Source current		1.7	A
I_{SM}	Source current (Pulsed)		6.8	A
P_D	Maximum power dissipation		1.6	W
T_{ch}	Channel temperature		$-55 \sim +150$	°C
T_{stg}	Storage temperature		$-55 \sim +150$	°C
—	Weight	Typical value	0.07	g

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V(BR)DSS	Drain-source breakdown voltage	Id = 1mA, VGS = 0V	20	—	—	V
IGSS	Gate-source leakage current	VGS = ±10V, VDS = 0V	—	—	±0.1	μA
IDSS	Drain-source leakage current	VDS = 20V, VGS = 0V	—	—	0.1	mA
VGS(th)	Gate-source threshold voltage	Id = 1mA, VDS = 10V	0.5	0.9	1.3	V
rDS(on)	Drain-source on-state resistance	Id = 6A, VGS = 4V	—	25	30	mΩ
rDS(on)	Drain-source on-state resistance	Id = 3A, VGS = 2.5V	—	32	40	mΩ
VDS(on)	Drain-source on-state voltage	Id = 6A, VGS = 4V	—	0.15	0.18	V
yfs	Forward transfer admittance	Id = 6A, VDS = 10V	—	13	—	S
Ciss	Input capacitance	VDS = 10V, VGS = 0V, f = 1MHz	—	900	—	pF
Coss	Output capacitance		—	300	—	pF
Crss	Reverse transfer capacitance		—	170	—	pF
td(on)	Turn-on delay time	VDD = 10V, Id = 3A, VGS = 4V, RGEN = RGS = 50Ω	—	25	—	ns
tr	Rise time		—	65	—	ns
td(off)	Turn-off delay time		—	95	—	ns
tf	Fall time		—	90	—	ns
VSD	Source-drain voltage	IS = 1.7A, VGS = 0V	—	0.75	1.1	V
Rth(ch-a)	Thermal resistance	Channel to ambient	—	—	78.1	°C/W
trr	Reverse recovery time	IS = 1.7A, dis/dt = -50A/μs	—	100	—	ns

PERFORMANCE CURVES

